



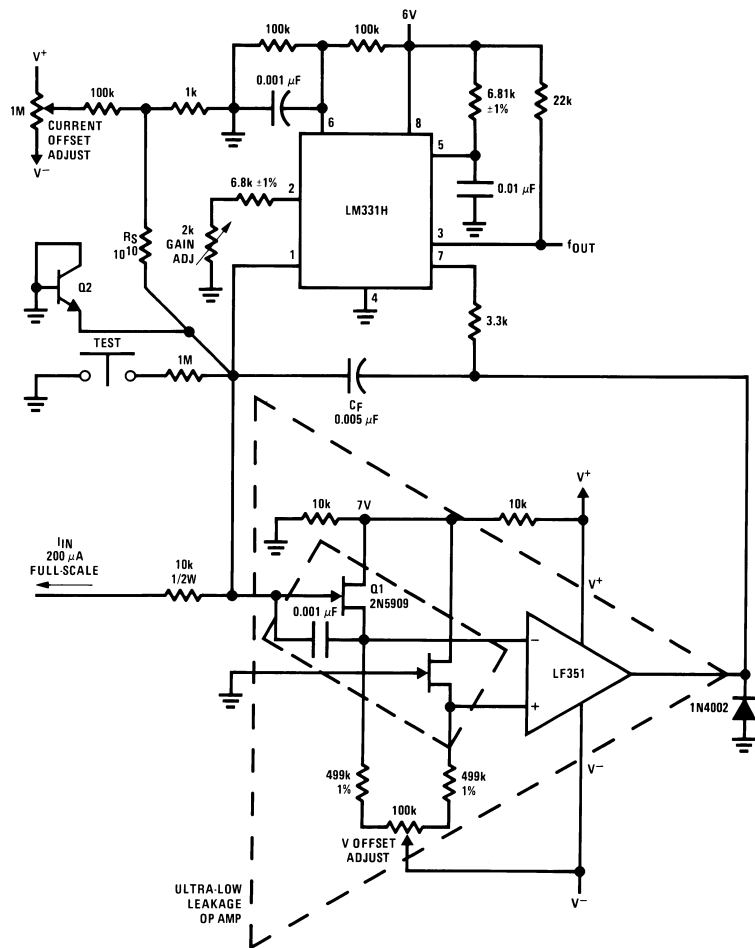
After trimming this circuit for a low offset when  $I_{IN}$  is 1 nA, the circuit will operate with an input range of 120 dB, from 200  $\mu$ A to 100 pA, and an accuracy or linearity error well below (0.02% of the signal plus 0.0001% of full-scale).

The circuit diagram shows a precision current source. The LM331 timer is configured with its non-inverting input (pin 1) connected to a voltage divider consisting of a 100k resistor and a 560 resistor, with a 100M resistor connected to the output (pin 7). The inverting input (pin 2) is connected to a 2k potentiometer (labeled '2k GAIN ADJUST') and a 6.81k  $\pm 1\%$  resistor. The output (pin 7) is connected to a 3.3k resistor and a 0.02  $\mu\text{F}$  capacitor (labeled  $C_F$ ). The timer's supply pins are connected to  $V^+$  (pin 8) and ground (pin 4). The LF351 op-amp is configured as a voltage follower, with its non-inverting input (pin 7) connected to the output of the LM331's output network and its output (pin 6) connected to the inverting input (pin 2). The op-amp's supply pins are connected to  $V^+$  (pin 7) and  $V^-$  (pin 4). The output of the op-amp (pin 6) is connected to a diode D3 (1N4002) and ground. The current source output is taken from the node between the 100M resistor and the 100k resistor, which is also connected to a 100 TO 10k resistor and a 200  $\mu\text{A}$  full-scale current source ( $I_{IN}$ ).

**FIGURE 2. Practical Wide-Range Current-to-Frequency Converter**

The voltage offset adjust pot is used to bring the summing point within a millivolt of ground. With an input signal big enough to cause  $f_{OUT}=1$  second per cycle, trim the V offset adjust pot so that closing the *test* switch makes no effect on

1. Run the LM331 on 5V to 6V to keep leakage down and to cut the dissipation and temperature rise, too.
2. Run the FETs with a 6V drain supply.
3. Guard all summing point wiring away from all other voltages.



Q1 - 2N5909 or similar  
 1G<1 pA  
 Q2 - 2N930 or 2N3565

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FIGURE 3. Very-Wide-Range Current-to-Frequency Converter

An alternate approach, shown in *Figure 4*, uses an LM11C as the input pre-amplifier. The LM11C has much better voltage drift than any of the other amplifiers shown here (normally less than 2  $\mu\text{V}/^\circ\text{C}$ ) and excellent current drift, less than 1  $\text{pA}/^\circ\text{C}$  by itself, and typically 0.2  $\text{pA}/^\circ\text{C}$  when trimmed with the 2N3904 bias current compensation circuit as shown. Of course, the LM331's leakage of 1  $\text{pA}/^\circ\text{C}$  will still double every 10 $^\circ\text{C}$ , so that having an amplifier with excellent  $I_b$  characteristics does not solve the whole problem, when trying to get good accuracy with a 100 pA signal. For that job, even the leakage of the LM331 must be guarded out!

What if even lower ranges of input current must be accepted? While it might be possible to use a current-to-voltage converter ahead of a V-to-F converter, offset voltage drifts would hurt dynamic range badly. Response and zero-drift of such an I-V will be disappointing. Also, it is not feasible to starve the LM331 to an arbitrary extent.

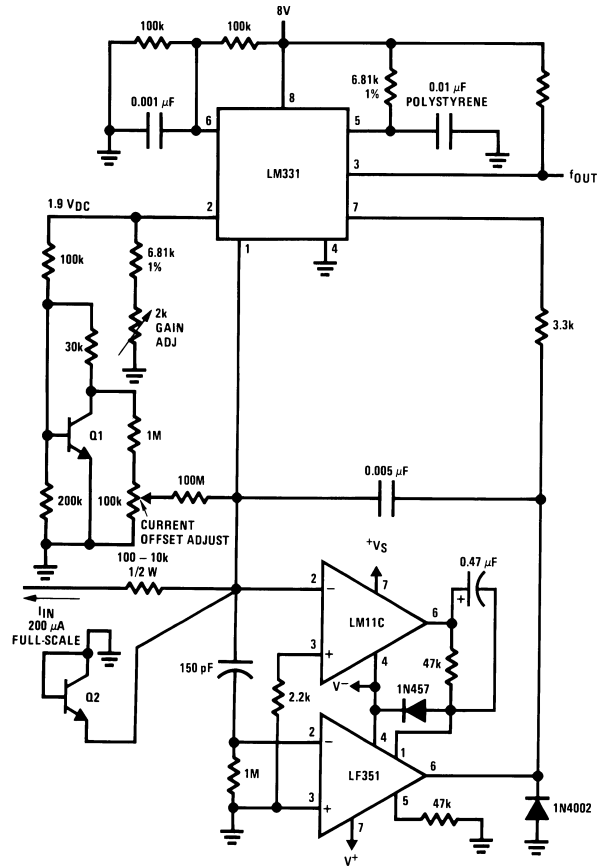
For example, while its  $I_{\text{OUT}}$  (full-scale) of 280  $\mu\text{A}$  DC can be cut to 10  $\mu\text{A}$  or 28  $\mu\text{A}$ , it cannot be cut to 1  $\mu\text{A}$  or 2.8  $\mu\text{A}$  with good accuracy at 10 kHz, because the internal switches in the integrated circuit will not operate with best speed and precision at such low currents.

Instead, the output current from pin 1 of the LM331 can be fed through a current attenuator circuit, as shown in *Figure 5*. The LM334 (temperature-to-current converter IC) causes -120 mV bias to appear at the base of Q2. When a current flows out of pin 1 of the LM331, 1/100 of the current will flow out of Q1's collector, and the rest will go out of Q2's collector. As the LM334's current is linearly proportional to Kelvin temperature, the -120 mV at Q2's base will change linearly with temperature so that the Q1/Q2 current divider stays at 1:100, invariant of temperature, according to the equation:

$$i_1/i_2 = e^{\frac{q(V_{b1} - V_{b2})}{kT}}$$

This current attenuator will work stably and accurately, even at high speeds, such as for 4  $\mu$ S current pulses. Thus, the output of Q1 is a charge pump which puts out only 10 pico-

coulombs per pulse, with surprisingly good accuracy. Note also that the LM331's leakage is substantially attenuated also, by a factor of 100 or more, so that source of error virtually disappears. When Q1 is off, it is really *OFF*, and its leakage is typically 0.01 pA if the summing point is within a millivolt or two of ground.



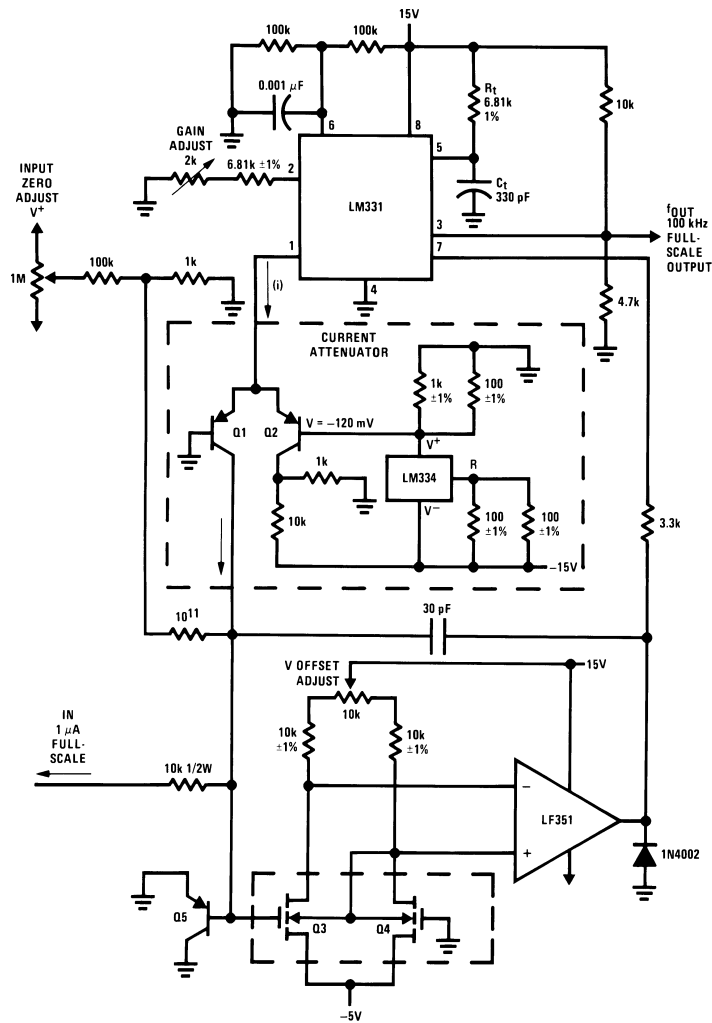
Q1, 2N3904 or any silicon NPN  
Q2, 2N930 or 2N3565

FIGURE 4. Very-Wide-Range I-to-F Converter with Low Voltage Drift

To do justice to this low leakage of the VFC, the op amp should be made with MOSFETs for Q3 and Q4, such as the Intersil 3N165 or 3N190 dual MOSFET (with no gate-protection diodes). When MOSFETs have relatively poor offset voltage, offset voltage drift, and voltage noise, this circuit does not care much about these characteristics, but instead takes advantage of the MOSFET's superior current leakage and current drift.

Now, with an input current of 1  $\mu$ A, the full-scale output frequency will be 100 kHz. At a 1 nA input, the output frequency

will be 100 Hz. And, when the input current is 1 pA, the output frequency will drop to 1 cycle per 10 seconds or 100 mHz. When the input current drops to zero, frequencies as small as 500  $\mu$ Hz have been observed, at 25°C and also as warm as 35°C. Here is a wide-range data converter whose zero drift is *well* below 1 ppm per 10°C! (Rather more like 0.001 ppm per °C.) The usable dynamic range is better than 140 dB, with excellent accuracy at inputs between 100% and 1% and 0.01% and 0.0001% of full-scale.



Q1, Q2, Q5 - 2N3906, 2N4250 or similar  
 Q3, Q4 - 3N165, 3N190 or similar. See text  
 Keep Q1, Q2 and LM334 at the same temperature

**FIGURE 5. Picoampere-to-Frequency Converters**

If a positive signal is of interest, the LM331 can be applied with a current reflector as in *Figure 6*. This current reflector has high output impedance, and low leakage. Its output can go directly to the summing point, or via a current attenuator made with NPN transistors, similar to the PNP circuit of *Figure 5*. This circuit has been observed to cover a wide (130 dB) range, with 0.1% of signal accuracy.

What is the significance of this wide-range current-to-frequency converter? In many industrial systems the question of using an inexpensive 8-bit converter instead of an expensive 12-bit data converter is a battle which is de-

cided everyday. But if the signal source is actually a current source, then you can use a V-to-F converter to make a cheap 14-bit converter or an inexpensive converter with 18 bits of dynamic range. The choice is yours.

Why use an I-to-F converter?

- It is a natural form of A-to-D conversion.
- It naturally facilitates integration, as well.
- There are many signals in the world, such as photospectrometer currents, which like to be digitized and integrated as a standard part of the analysis of the data.

- Why have a fast frequency out?

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**FIGURE 6. Current-to-Frequency Converter For Positive Signals**



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